

15 Watts • 50 Volts • 4.5mS, 35% 1200–1400MHz

E Class Earless Driver GaN Transistor – Key Features

- 1200-1400MHz 15W Output Power CW and Pulsed
- Common Source Class AB 50VDD Bias Voltage
- >60% Efficiency Across the Frequency Band
- Extremely Compact Size
- 17.8 dB Typical Power Gain
- 0.3 dB Typical Excellent Gain Flatness
- L-Band Radars, Communication, Industrial, General Purpose
- · All gold metallization and eutectic die attach for highest reliability
- 50Ω in/out lumped element very small footprint plug & play pallets available

CASE/PALLET OUTLINES



55-QQP (0.160"x0.230")

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation

Device Dissipation @ 25°C 34 W

Maximum Voltage and Current

Drain-Source Voltage (VDSS) 150 V Gate-Source Voltage (VGS) -8 to +0 V

Maximum Temperatures

Storage Temperature (TSTG) -55 to +125° C

Operating Junction Temperature +200 °C

ELECTRICAL CHARACTERISTICS @ 25°C

Symbol	Characteristics	stics Test Conditions		Тур	Max	Units
Pout	Output Power	Pin=0.32W, Freq=1200,1300,1400 MHz	15	19		W
Gp	Power Gain	Pin=0.32W, Freq=1200,1300,1400 MHz	16.7	17.8		dB
ηd	Drain Efficiency	Pin=0.32W, Freq=1200,1300,1400 MHz	50	68		%
Dr	Droop	Pin=0.32W, Freq=1200,1300,1400 MHz		0.2	0.6	dB
VSWR-T	Load Mismatch Tolerance	Pin=0.32W, Freq=1300MHz,100μ-10%			10:1	·

• Bias Condition: Vdd=+50V, Idq=10mA constant current (Vgs= -2.0 ~ -4.5V typical)

FUNCTIONAL CHARACTERISTICS @ 25°C

I _{D(Off)}	Drain leakage current	V _{GS} = -8V, V _D = 50V		1.0	mA
$I_{G(Off)}$	Gate leakage current	$V_{GS} = -8V$, $V_D = 0V$		0.2	mA
BV _{DSS}	Drain-source breakdown voltage	$V_{GS} = -8V$, $I_D = 2mA$	150		V

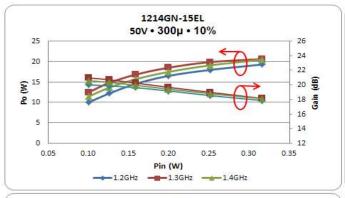
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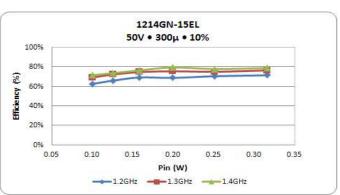


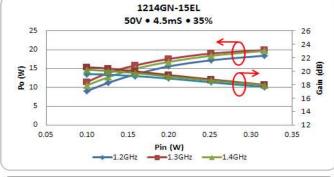
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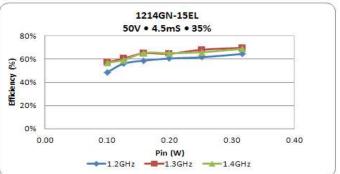
TYPICAL BROAD BAND PERFORMACE DATA

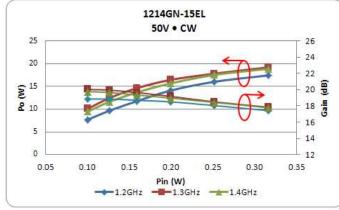
Frequency	Pin (mW)	Pout (W)	ld (mA)	RL (dB)	Nd (%)	G (dB)	Droop (dB)
1200 MHz	320	18.5	.210	-7.5	65	17.7	0.2
1300 MHz	320	20.0	.210	-8.0	70	18.0	0.2
1400 MHz	320	19.7	.210	-7.5	69	17.9	0.2

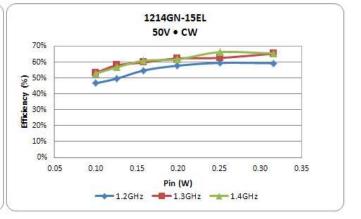












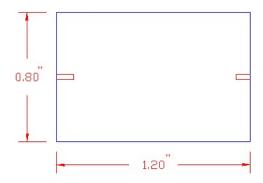


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Critical Performance @ Pin = 25dBm

Freq (GHz)	Test Condition	Po (W)	Gain (dB)	Eff (%)	Droop (dB)
1.2	300μS – 10%	19.3	17.9	70	0.1
1.3	4.5mS – 35%	18.5	17.7	65	0.2
1.4	CW	17.5	17.4	58	0.0
1.2	300μS – 10%	20.6	18.2	75	0.1
1.3	4.5mS – 35%	20.0	18.0	70	0.2
1.4	CW	19.2	17.8	65	0.0
1.2	300μS – 10%	20.5	18.1	76	0.1
1.3	4.5mS – 35%	19.7	18.0	69	0.2
1.4	CW	18.9	17.8	65	0.0

Test Fixture Overall Dimension



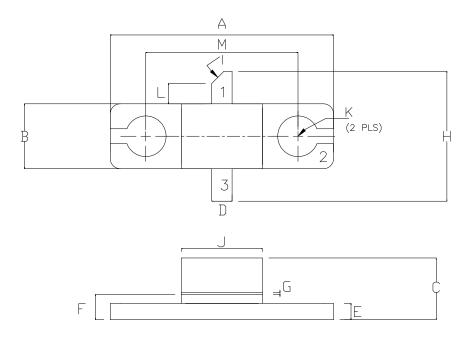
(Dimensions shown are in inches)

Test Fixture available upon request



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1214GN-15E CASE OUTLINE 55-QQ PACKAGE DIMENSION



Dim	Millimeter	Tol	Inches	Tol
Α	13.970	0.250	0.550	0.010
В	4.570	0.250	0.160	0.010
С	3.860	0.330	0.152	0.013
D	1.270	0.130	0.050	0.005
E	1.020	0.130	0.040	0.005
F	1.700	0.130	0.067	0.005
G	0.130	0.025	0.005	0.001
Н	8.130	0.250	0.320	0.010
1	45°	5°	45°	5°
J	5.080	0.250	0.200	0.010
K	2.54 DIA	0.130	.100 DIA	0.005
L	1.270	0.130	0.050	0.005
M	9.530	0.130	0.375	0.005

PIN 1: DRAIN PIN 2: SOURCE PIN 3: GATE





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Revision History

Revision Level / Date	Para. Affected	Description
0.2 / 04 Dec. 2014	•	Initial Preliminary Release

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